



FDMF6730 Driver plus FET Multi-chip Module

Features

- Over 95% efficiency
- Internal 5V regulator for gate drive
- 6V-16V input range
- 1MHz max operating frequency
- SMOD operation capability for light load efficiency
- 5A current capability (10A with PASS FET)
- Current limit set by $R_{\text{DS(on)}}$ sensing to minimize power losses
- Integrated bootstrap diode

Applications

- Ultra Mobile PC
- Notebook Computers

General Description

The FDMF6730 is a high efficiency Driver plus MOSFET power stage solution optimized for Ultra Mobile PC (UMPC) system power voltage supplies. It is fully compliant with the Intel Ultra-Mobile Driver MOS (uDrMOS) Specification. The MOSFETs and driver have been optimized to perform with high efficiency at light and medium loads, ideal for compact PC devices.

The internal driver IC integrates two highly efficient LDOs for internal gate-drive and external circuitry. The bootstrap diode is also integrated within the IC. When operating with a single low side MOSFET the uDrMOS module is capable of delivering up to 5A of continuous current. The PASS transistor may be easily routed in parallel with the low side MOSFET to provide up to 10A. The module also incorporates an over current protection flag from an $R_{\text{DS(on)}}$ current sense architecture.

The device comes in a 6X6 Power QFN package for improved thermal performance.

Typical Application

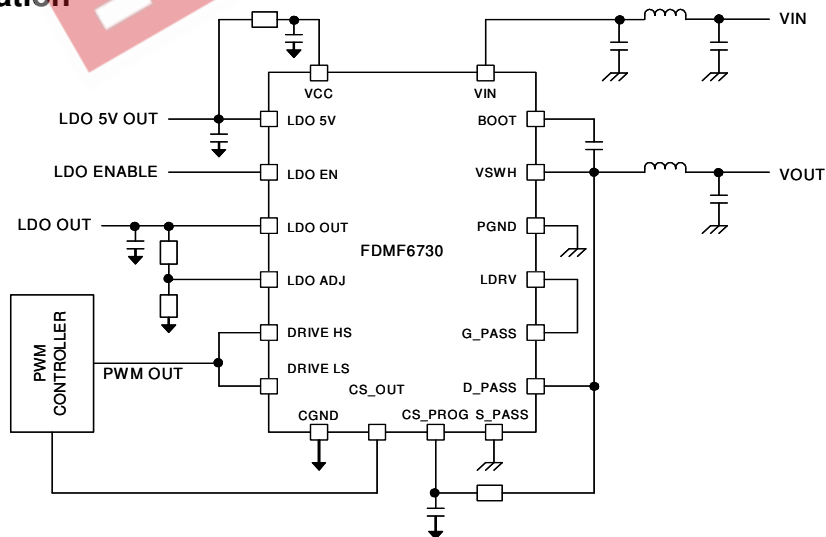


Figure 1. Power Train Application Circuit

Ordering Information

| Part | Current Rating Max [A] | Input Voltage Typical [V] | Frequency Max [KHz] | Device Marking |
|----------|------------------------------|---------------------------------|---------------------------|-------------------|
| FDMF6730 | 10 | 6-16 | 1000 | FDMF6730 |

Functional Block Diagram

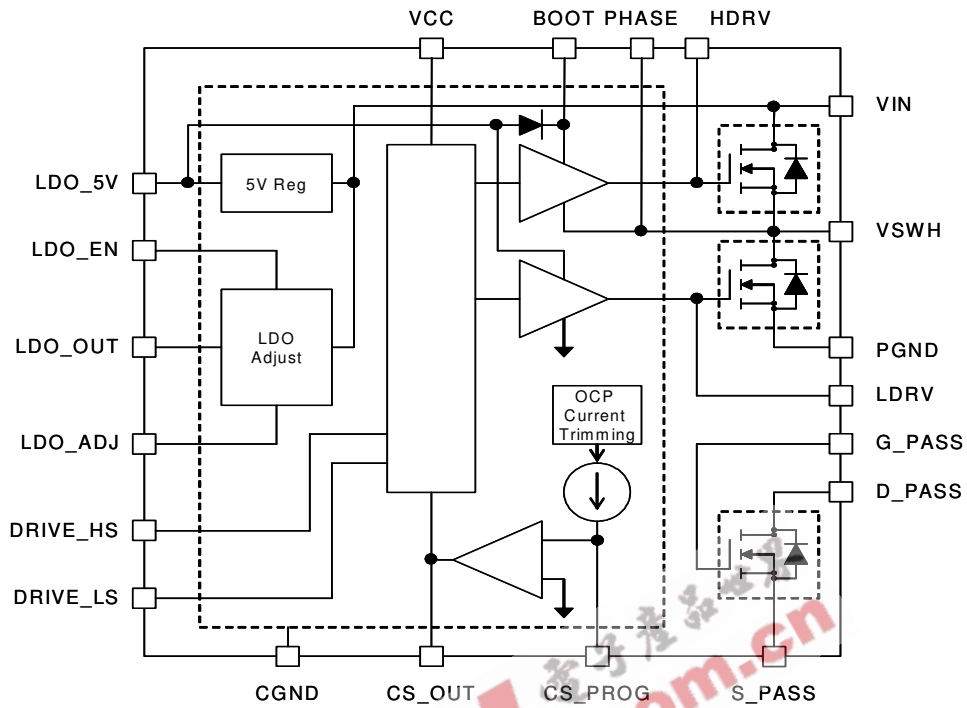


Figure 2. Functional Block Diagram

Pin Configuration

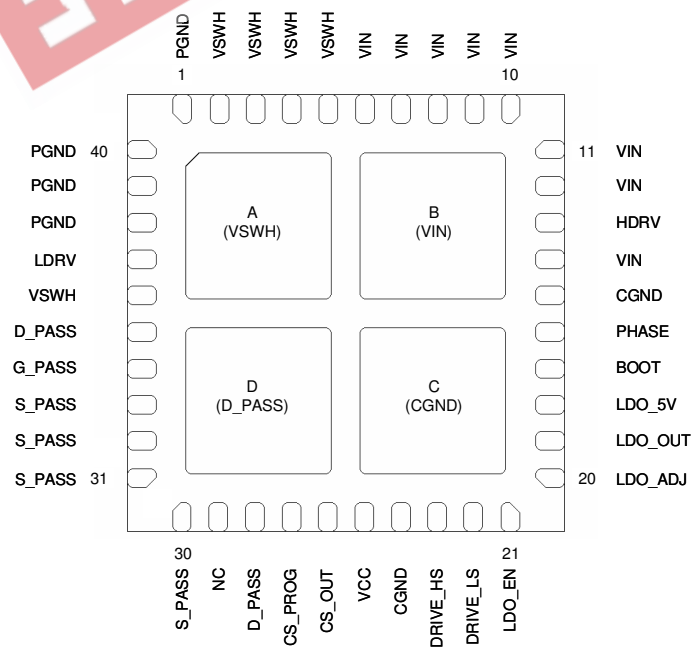


Figure 3. 6mm X 6mm, 40L MLP Bottom View

Pin Description

| Pin | Name | Function |
|--------------|----------|--|
| 1, 38 - 40 | PGND | Low Side FET Source Pin. Connect to GND |
| 2 - 5, 36, A | VSWH | Switch Node Pin. Low Side FET Drain pin. Electrically shorted to PHASE pin |
| 6 - 12,14,B | VIN | Input Voltage Pin. Input voltage for buck converter |
| 13 | HDRV | HDRV pin. High Side driver output. Connected to High Side FET gate pin. |
| 15, 24, C | CGND | IC Ground. Ground return for driver IC. |
| 16 | PHASE | Switch Node Pin for easy bootstrap capacitor routing. Electrically shorted to VSWH pin. |
| 17 | BOOT | Bootstrap Supply Input Pin. Provides voltage supply to high-side MOSFET driver. Connect bootstrap capacitor. |
| 18 | LDO_5V | 5V Internal LDO Output. |
| 19 | LDO_OUT | Adjustable LDO Output. |
| 20 | LDO_ADJ | LDO Adjust Input. Connect to external voltage divider to adjust LDO output. |
| 21 | LDO_EN | Adjustable LDO Enable Pin. 1 = Enable, 0 = Disable |
| 22 | DRIVE_LS | Low Side PWM Input. Connect to PWM controller. |
| 23 | DRIVE_HS | High Side PWM Input. Connect to PWM controller. |
| 25 | VCC | Driver VCC. Connect to 5V. |
| 26 | CS_OUT | Current Sense Output. 1 = Over-current Fault, 0 = No Fault. |
| 27 | CS_PROG | Current Sense Program. |
| 28, 35, D | D_PASS | Pass FET Drain Pin. Connect to VSWH pad for higher output current. |
| 29 | NC | No Connect. This pin must be floated. Must not be connected to any pin. |
| 30-33 | S_PASS | Pass FET Source Pin. Connect to PGND pad for higher output current. |
| 34 | G_PASS | Pass FET Gate Pin. Connect to LDRV pin for higher output current. |
| 37 | LDRV | LDRV pin. Low Side driver output. Connect to G_PASS pin for higher output current. |

Absolute Maximum Rating

Stresses exceeding the absolute maximum rating may damage the device. The device may not function or be operable above the recommended operating conditions and stressing these parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect the device reliability. The absolute maximum rating are stress ratings only.

| Parameter | Min. | Max. | Units |
|---|--|------|---------------|
| V_{CC} , Drive_LS, Drive_HS, LDO_EN, CS_Prog, CS_Out to GND | -0.3 | 6 | V |
| V_{IN} to PGND | -0.3 | 20 | V |
| BOOT to VSWH | -0.3 | 6 | V |
| VSWH to PGND | -1.0 | 27 | V |
| BOOT to PGND | -0.3 | 27 | V |
| $I_{O(AV)}$ | $V_{IN} = 8.4V, V_O = 3.3V, f_{SW} = 1MHz, T_{PCB} = 130^{\circ}C$ | | A |
| $I_{O(PK)}$ | $V_{IN} = 8.4V, t_{PULSE} = 10\mu s$ | | A |
| $R_{\theta JPCB}$ | Junction to PCB Thermal Resistance note 1. | | $^{\circ}C/W$ |
| P_T | $T_{PCB} = 130^{\circ}C$ | | W |
| Operating and Storage Junction Temperature Range | | | |
| | -55 | 150 | $^{\circ}C$ |

Note 1: Package power dissipation based on 4 layer, 2 square inch, 2 oz. copper pad. $R_{\theta JPCB}$ is the steady state junction to PCB thermal resistance with PCB temperature referenced at VSWH pin.

Recommended Operating Range

The recommended operating conditions table defines the conditions for actual device operation. These conditions are specified to ensure optimal performance to the datasheet specification. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Parameter | | Min. | Typ. | Max. | Units |
|------------------|--------------------------------|------|------|------|-------|
| V _{CC} | Control Circuit Supply Voltage | 4.5 | 5 | 5.5 | V |
| V _{IN} | Output Stage Supply Voltage | 6 | 8.4 | 16 | V |
| V _{OUT} | Output Voltage | 1.5 | 3.3 | 5 | V |

Electrical Characteristics

V_{IN} = 8.4V, V_{CC} = 5V, T_A = 25°C unless otherwise noted.

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Units |
|--|----------------------|--|------|------|------|-------|
| Input Voltage Range | V _{IN} | | 6 | | 16 | V |
| Operating Quiescent Current | | | | | 2 | mA |
| Drive_HS, Drive_LS, LDO_EN Logic Inputs | | | | | | |
| High Level Input | V _{IH} | | 2.4 | | | V |
| Low Level Input | V _{IL} | | | | 0.4 | V |
| Input Current | | | -2 | | 2 | μA |
| 5V LDO | | | | | | |
| Output Voltage | | | 4.7 | 5 | 5.3 | V |
| Line Regulation | | 6V < V _{IN} < 16V | | 5 | | mV |
| Load Regulation | | 5mA < I _{LOAD} < 100mA | | 75 | | mV |
| Short Circuit Current Limit | | | 100 | 180 | | mA |
| Adjustable LDO | | | | | | |
| Adjust Voltage | V _{ADJ} | | 0.58 | 0.6 | 0.62 | V |
| Line Regulation | | 6V < V _{IN} < 16V | | 3 | | mV |
| Load Regulation | | 5mA < I _{LOAD} < 100mA | | 11 | | mV |
| Short Circuit Current Limit | | | 100 | 180 | | mA |
| Adjust Input Bias Current | | | | | 0.2 | μA |
| Over Current Protection | | | | | | |
| CS_Prog Current | | | 30 | 40 | 50 | μA |
| Thermal Shutdown | | | | | | |
| Threshold | | | | 150 | | °C |
| Hysteresis | | | | 19 | | °C |
| Propagation Delay | | | | | | |
| 250ns Timeout | t _{TIMEOUT} | VSWH = 2V, HDRV from HI to LO and LDRV from LO to HI | | 250 | | ns |
| | t _{DTHH} | LDRV going LO to VSWH going HI | | 30 | | ns |
| | t _{PDHL} | Drive_LS going HI to HDRV going LO | | 10 | | ns |
| | t _{DTLH} | VSWH going LO to LDRV going HI | | 20 | | ns |
| | t _{PDLL} | Drive_LS going LO to LDRV going LO | | 10 | | ns |

Description of Operation

2-Bit PWM Input

The PWM input is composed of a high side drive and a low side drive input which control the high side and low side FETs respectively. They can also be setup to provide asynchronous rectification (low FET off) and phase shutoff (both FETs off).

Truth Table

| DRIVE_LS | DRIVE_HS | Low Side MOSFET | High Side MOSFET |
|----------|----------|-----------------|------------------|
| 0 | 0 | OFF | OFF |
| 0 | 1 | OFF | ON |
| 1 | 0 | ON | OFF |
| 1 | 1 | OFF | OFF |

PASS FET

One of the most unique features of the uDrMOS is the integrated Pass FET. The pass FET can be easily routed in parallel with the low side FET in order to provide up to 10A of current. When not used as part of the DC-DC controller, it can be used in other applications such as load switching, etc.

5V LDO

The uDrMOS conveniently incorporates a 5V LDO regulator to drive the internal logic of the IC and gates of the internal MOSFETs.

Adjustable LDO

Another feature of the part is the adjustable 100mA LDO. The LDO output voltage is easily configured with a resistor divider.

Current Limit

The part also has current limit flag which is set by an internal OCP topology.

Applications Section

Input Capacitor

A High frequency 4.7 ceramic X5R must be connected directly from V_{IN} to GND

Bootstrap Circuit

The bootstrap circuit uses a charge storage capacitor and an external diode. A minimum of 0.1 μ F high frequency capacitor must be connected between the BOOT and PHASE pin. The PHASE pin is already internally connected to the switch-node.

5V LDO

A minimum of 4.7 μ F ceramic X5R type must be connected from LDO_5V pin to GND to ensure stable operation and to provide high frequency bypassing for low side driver. This LDO can provide power to the internal logic circuitry and gate drivers via a 100Ohm resistor. A high frequency 1 μ F ceramic capacitor must be placed from V_{CC} to GND.

Adjustable LDO

A minimum of 10 μ F ceramic X5R type must be connected close from this pin to GND to insure stable operation for a range of 2.5V to 5V outputs. For output voltages of 0.6V to 2.5V the minimum capacitance must be 22 μ F ceramic type. A minimum of 1mA load current must be connected from this pin to GND. LDO_ADJ voltage 0.6V typical.

LDO_EN: Adjustable LDO enable pin (1= Enable, 0= Disable)

Over Current Protection

A resistor connected from the VSWH pin and this pin programs the over current threshold point. CS_OUT is the output of an internal current sense comparator which switches high when the current in low side MOSFET exceeds a pre program level set by the CS_PROG pin. This pin is low during normal operation.

Typical Characteristics

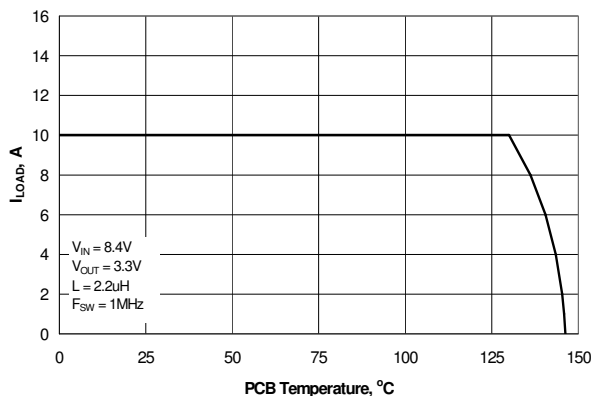


Figure 4. Safe Operating Area

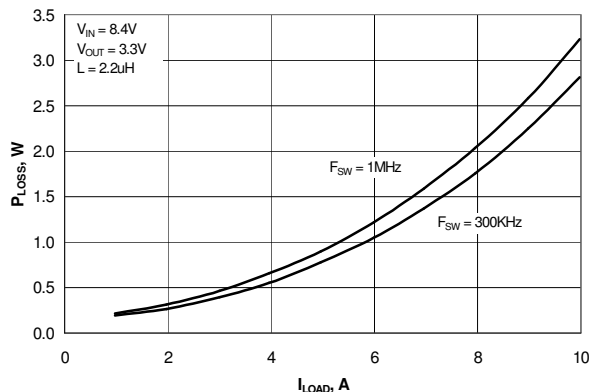


Figure 5. Power Loss vs. Output Current

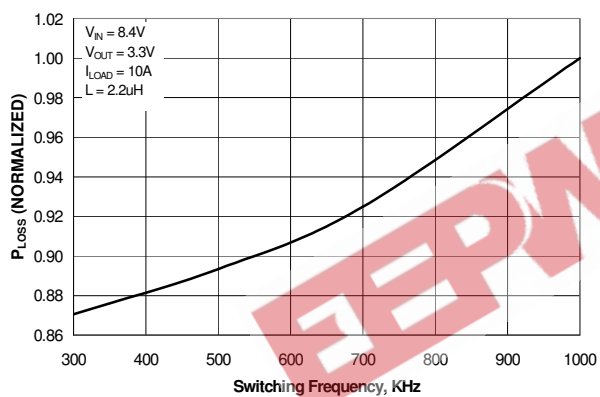


Figure 6. Power Loss vs. Switching Frequency

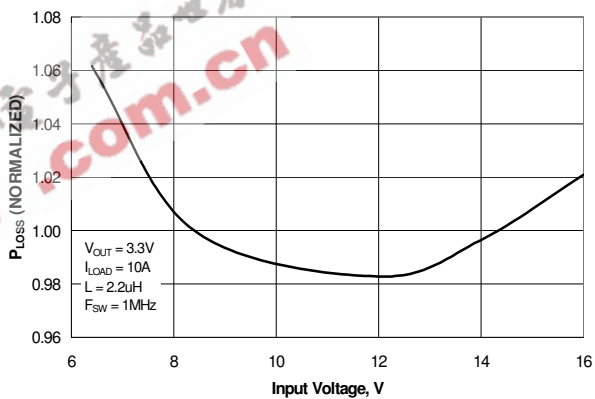


Figure 7. Power Loss vs. Input Voltage

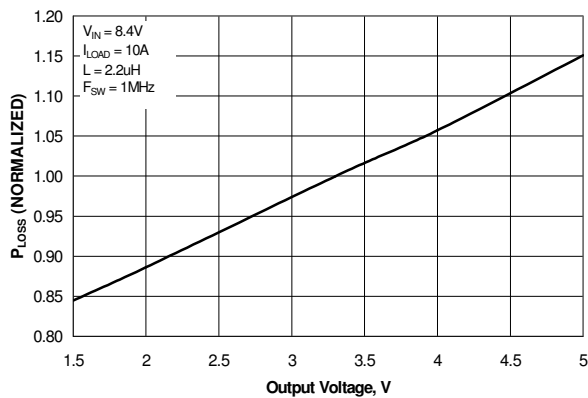


Figure 8. Power Loss vs. Output Voltage

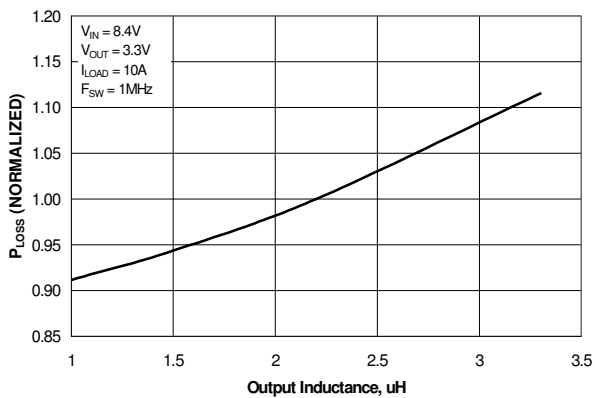


Figure 9. Power Loss vs. Output Inductance

Typical Characteristics

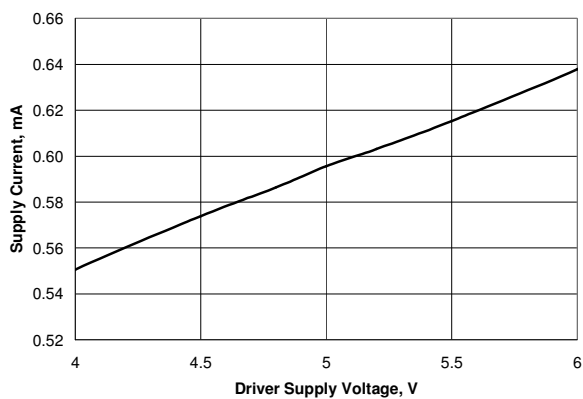


Figure 10. Supply Current vs. Driver Supply

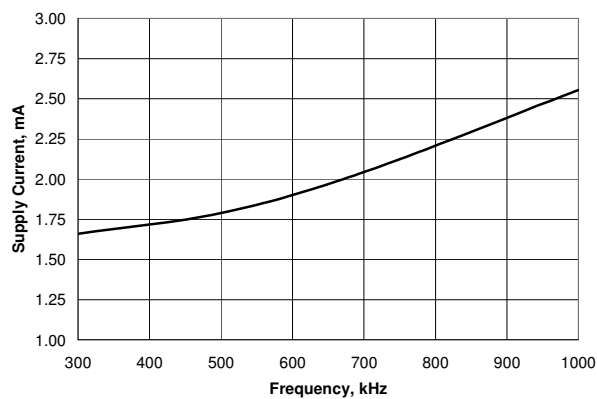


Figure 11. Supply Current vs. Frequency

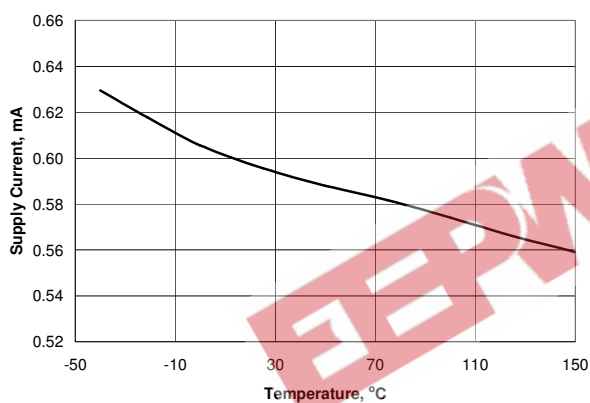


Figure 12. Supply Current vs. Temperature

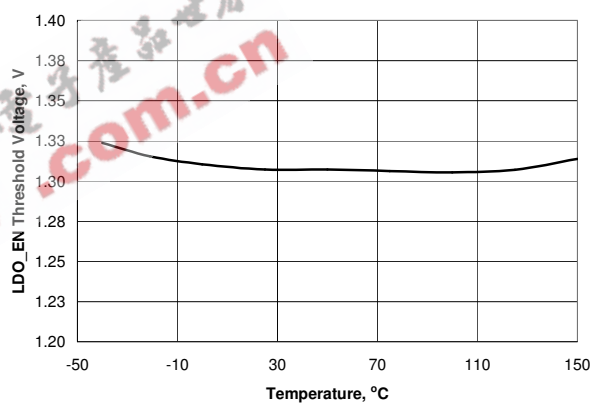


Figure 13. LDO_EN Threshold Voltage vs. Temperature

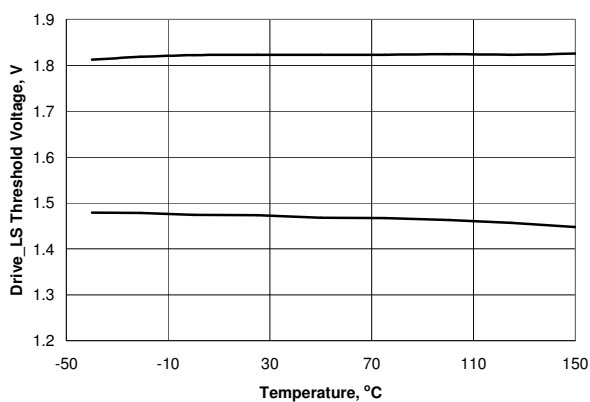


Figure 14. Driver_LS Threshold Voltage vs. Temperature

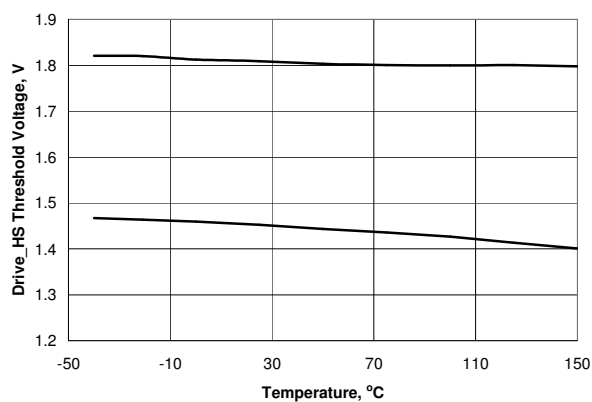


Figure 15. Driver_HS Threshold Voltage vs. Temperature

Typical Characteristics

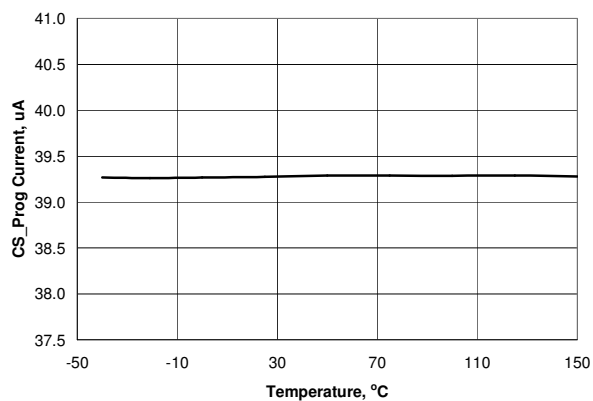
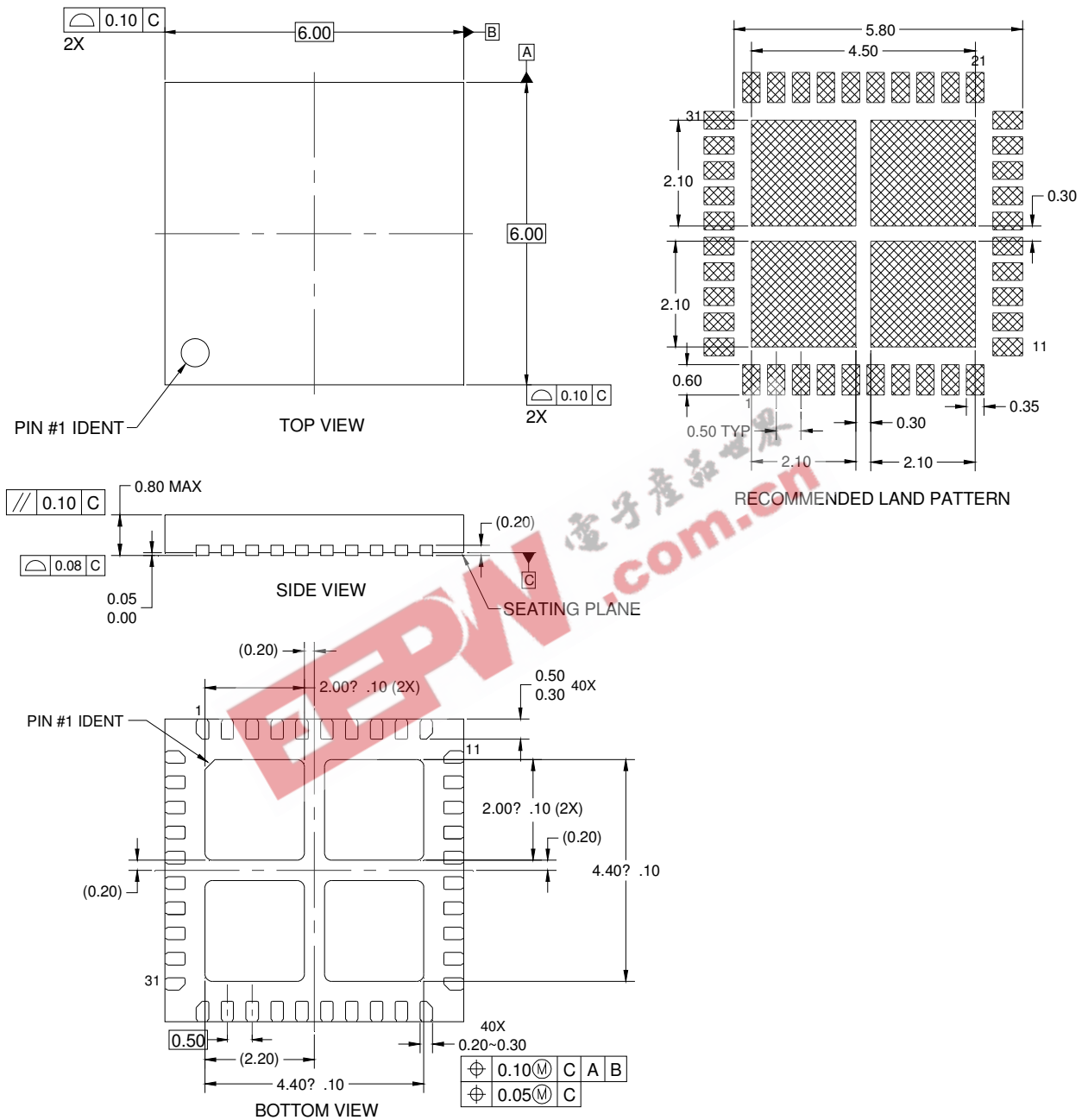


Figure 16. CS_Prog Current vs. Temperature

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Dimensional Outline and Pad layout



NOTES:

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- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994
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